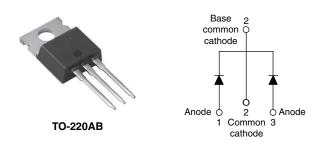
# VS-MBR20...CTHN3 Series

**Vishay Semiconductors** 

### www.vishay.com

# High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMMARY						
I <sub>F(AV)</sub>	2 x 10 A					
V <sub>R</sub>	35 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.57 V					
I <sub>RM</sub> max.	15 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
E <sub>AS</sub>	8 mJ					
Package	TO-220AB					
Diode variation	Common cathode					

### FEATURES

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	OL CHARACTERISTICS VALUES U							
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	A					
V <sub>RRM</sub>		35/45	V					
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C (per leg)	20	٨					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	A					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V					
TJ	Range	-65 to 150	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBR2035CTHN3	VS-MBR2045CTHN3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	35	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	35	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST	VALUES	UNITS				
Maximum average per leg		$T = 125 ^{\circ}\text{C}$ roted V		10				
forward current per device	I <sub>F(AV)</sub>	$T_{C}$ = 135 °C, rated $V_{R}$		20				
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	kHz, T <sub>C</sub> = 135 °C	20				
Non-repetitive peak surge current	I <sub>FSM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	A			
		Surge applied at rated load condition half wave, single phase, 60 Hz		150				
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to Frequency limited by T <sub>J</sub> ma	2					
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4$	mH	8	mJ			

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		20 A	T <sub>J</sub> = 25 °C	0.84				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T.I = 125 °C	0.57	V			
		20 A	IJ = 125 C	0.72				
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Dated DC valtage	0.1	m (			
Maximum instantaneous reverse current	IRM \"	T <sub>J</sub> = 125 °C	Rated DC voltage	15	mA			
Threshold voltage	V <sub>F(TO)</sub>	T T maximum		0.354	V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		17.6	mΩ			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	600	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of tern	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temper	ature range	TJ		-65 to 150	°C			
Maximum storage tempera	ature range	T <sub>Stg</sub>		-65 to 175	U			
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	2.0	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (only for TO-220)	0.50	0/11			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm			
Mounting torque maximum			Non-lubricated threads	12 (10)	(lbf ⋅ in)			
				MBR20	35CTH			
Marking device			Case style TO-220AB	MBR2045CTH				



## VS-MBR20...CTHN3 Series

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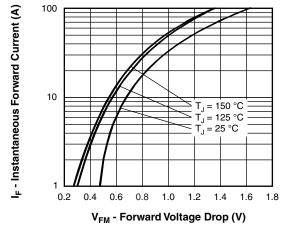


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

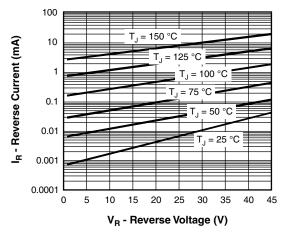


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

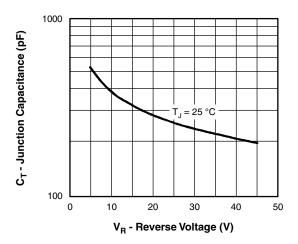


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

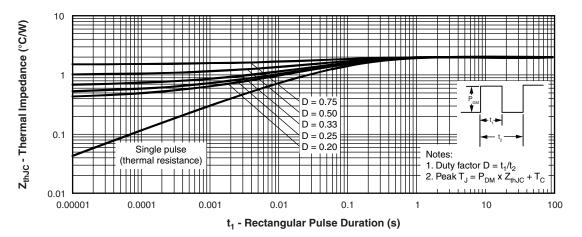
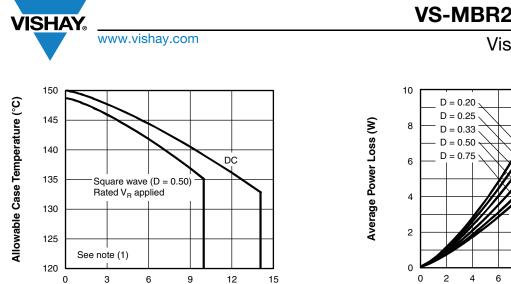


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

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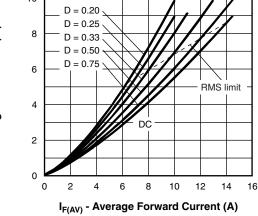


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

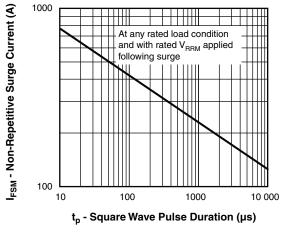


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

# VS-MBR20...CTHN3 Series



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### **ORDERING INFORMATION TABLE**

Device code	VS-	MBR	20	45	ст	н	N3
		2	(3)	4	5	6	7
	1 2 3 4 5 6	- Sch - Cur - Volt - CT - H =	ottky M rent rati age rati = Esser AEC-Q	ntial part 101 qua	es 20 A) number ilified	35 45	= 35 V = 45 V
	7			ntal digil logen-fre		S-comp	oliant, a

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBR2035CTHN3	50	1000	Antistatic plastic tube					
VS-MBR2045CTHN3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95222					
Part marking information TO-220AB-1	13 www.vishay.com/doc?95028					
SPICE model	www.vishay.com/doc?95295					

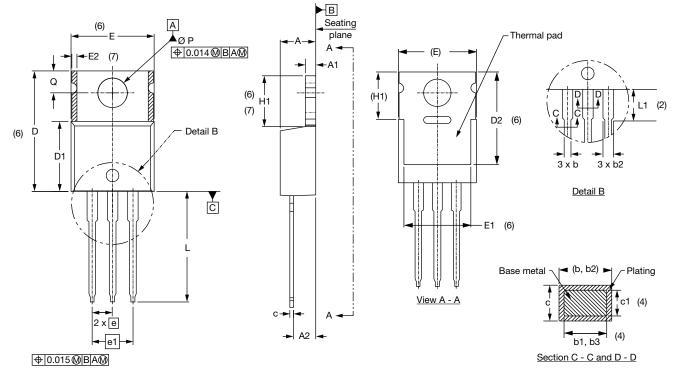
## **Outline Dimensions**



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**TO-220AB** 

### **DIMENSIONS** in millimeters and inches



Lead tip

reten Teten reten

Conforms to JEDEC<sup>®</sup> outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimensions: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1

- <sup>(7)</sup> Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC<sup>®</sup> TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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